THE UNITED STATES PATENT AND TRADEMARK OFFICE

REVOCATION AND NEW POWER OF ATTORNEY AND CHANGE OF CORRESPONDENCE ADDRESS

I, Dr. Graham Fisher, Director of Intellectual Property of MEMC Electronic Materials, Inc., the Assignee of the entire right, title, and interest in the U.S. Patent Application(s) and/or Patent(s) identified on the attached Schedule A, hereby revoke all previous powers of attorney or authorizations of agent given and do hereby appoint the attorneys or agents associated with the following Customer Number, with full power of substitution and revocation, to prosecute and transact all business in the Patent and Trademark Office connected therewith for the U.S. Patent Application(s) and/or Patent(s) listed in the attached Schedule A:

Customer Number: 76681

Please direct all correspondence in connection with said U.S. Patent Application(s) and/or Patent(s) to:

Customer Number: 76681

Respectfully submitted

100/

Dr. Graham Fisher
Director of Intellectual Property
MEMC Electronic Materials, Inc.

THE UNITED STATES PATENT AND TRADEMARK OFFICE

STATEMENT UNDER 37 CFR 3.73(b)

MEMC Electronic Materials, Inc., a Delaware Corporation, pursuant to 37 CFR 3.73(b), hereby states that it is the Assignee of the entire right, title, and interest in U.S. Patent Application(s) and/or Patent(s) on the attached Schedule A.

The entire rights, title, and interest in the aforementioned Patent Application(s) and/or Patent(s) were conveyed to MEMC Electronic Materials, Inc. via Assignment(s) recorded with the United States Patent and Trademark Office at the Reel/Frame Numbers on the attached Schedule A.

The undersigned, Dr. Graham Fisher, Director of Intellectual Property, has full authorization to act on behalf of Assignee MEMC Electronic Materials, Inc.

Respectfully submitted,

Date: 5/13/2008

Dr Graham Fisher

Director of Intellectual Property
MEMC Electronic Materials, Inc.

APPENDIX A Owned by MEMC Electronic Materials, Inc.

REFERENCE MEMCZ690 1 MEMCZ691 MEMCZ704 MEMCZ704 MEMCZ704 MEMCZ763	CONF. NO 1463 4480 6878 6472 22067 2338	PUBLICATION NO. & DATE DATE US-2001-0732580-A1 10/5-2001 US-2002-0584586-A7 744,2002 US-2002-0584586-A1	SERIAL NO. FILING DATE FILING	BATENT NO. ISSUE DATE (S. 819.319 117.20/2001 117.20/2001 10.20/2002 2.20/20	CURRENT OWNERY ASSIGNEE MEAC Electronic Miditarians, The MEAC Electronic Materials, Inc. MEAC Electronic MEAC Electronic MEAC Electronic MEAC Electronic MATERIA Electronic MATERIA Electronic MATERIA Electronic MATERIA Ele	REEL AND FRAME NO. TORISONER and OTZISSONER and OTZISSONER OTZISSONER OTZISSONER OTZISSONER OTZISSONER OTZISSONER	TITLE BARUIM DOPING OF MOLTEN SILLOON FOR USE IN CRYSTAL GROWING PROCESS GROWING PROCESS SEMICONDUCTOR WAFEN MANUFACTIRING PROCESS METHOD AND APPRACTE SOR PEEPARING MOLTEN BETHOD AND APPRACTE SOR PEEPARING MOLTEN EBALCONDUCTOR WAFEN FOLDER
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